

N-Channel Super Junction Power MOSFET II

General Description

The series of devices use advanced super junction technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

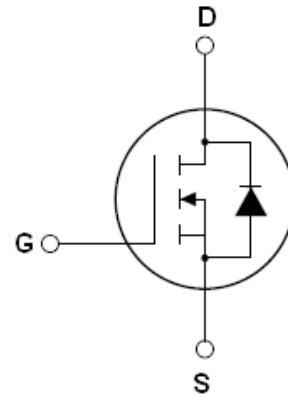
Features

- New technology for high voltage device
- Low on-resistance and low conduction losses
- Small package
- Ultra Low Gate Charge cause lower driving requirements
- 100% Avalanche Tested
- ROHS compliant

Application

- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)

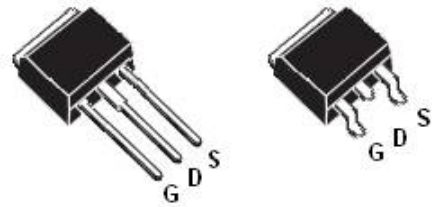
| | | |
|-------------------|------|------------|
| V_{DS} | 900 | V |
| $R_{DS(ON) TYP.}$ | 1000 | m Ω |
| I_D | 5 | A |



Schematic diagram

Package Marking And Ordering Information

| Device | Device Package | Marking |
|------------|----------------|------------|
| NCE90R1K2I | TO-251 | NCE90R1K2I |
| NCE90R1K2K | TO-252 | NCE90R1K2K |



TO-251

TO-252

Table 1. Absolute Maximum Ratings ($T_c=25^\circ\text{C}$)

| Parameter | Symbol | Value | Unit |
|--|-----------------|----------|---------------------|
| Drain-Source Voltage ($V_{GS}=0V$) | V_{DS} | 900 | V |
| Gate-Source Voltage ($V_{DS}=0V$) | V_{GS} | ± 30 | V |
| Continuous Drain Current at $T_c=25^\circ\text{C}$ | $I_{D(DC)}$ | 5 | A |
| Continuous Drain Current at $T_c=100^\circ\text{C}$ | $I_{D(DC)}$ | 3 | A |
| Pulsed drain current (Note 1) | $I_{DM(pluse)}$ | 15 | A |
| Maximum Power Dissipation($T_c=25^\circ\text{C}$) | P_D | 81 | W |
| Derate above 25°C | | 0.65 | W/ $^\circ\text{C}$ |
| Single pulse avalanche energy (Note 2) | E_{AS} | 140 | mJ |
| Avalanche current (Note 1) | I_{AR} | 2.5 | A |
| Repetitive Avalanche energy, t_{AR} limited by T_{jmax} (Note 1) | E_{AR} | 0.4 | mJ |

| Parameter | Symbol | Value | Unit |
|--|----------------|------------|------|
| Drain Source voltage slope, $V_{DS} \leq 480V$, | dv/dt | 50 | V/ns |
| Reverse diode dv/dt , $V_{DS} \leq 480V, I_{SD} < I_D$ | dv/dt | 5 | V/ns |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55...+150 | °C |

* limited by maximum junction temperature

Table 2. Thermal Characteristic

| Parameter | Symbol | Value | Unit |
|---|------------|-------|------|
| Thermal Resistance, Junction-to-Case (Maximum) | R_{thJC} | 1.54 | °C/W |
| Thermal Resistance, Junction-to-Ambient (Maximum) | R_{thJA} | 62 | °C/W |

Table 3. Electrical Characteristics (TA=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|--|--------------|--|-----|------|-----------|------------|
| On/off states | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=250\mu A$ | 900 | | | V |
| Zero Gate Voltage Drain Current($T_C=25^\circ C$) | I_{DSS} | $V_{DS}=900V, V_{GS}=0V$ | | | 1 | μA |
| Zero Gate Voltage Drain Current($T_C=125^\circ C$) | I_{DSS} | $V_{DS}=900V, V_{GS}=0V$ | | | 100 | μA |
| Gate-Body Leakage Current | I_{GSS} | $V_{GS}=\pm 30V, V_{DS}=0V$ | | | ± 100 | nA |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$ | 2.5 | 3 | 3.5 | V |
| Drain-Source On-State Resistance | $R_{DS(on)}$ | $V_{GS}=10V, I_D=2.5A$ | | 1000 | 1200 | m Ω |
| Dynamic Characteristics | | | | | | |
| Forward Transconductance | g_{FS} | $V_{DS} = 20V, I_D = 2.5A$ | | 5.5 | | S |
| Input Capacitance | C_{iss} | $V_{DS}=50V, V_{GS}=0V,$ $F=1.0MHz$ | | 680 | | pF |
| Output Capacitance | C_{oss} | | | 55 | | pF |
| Reverse Transfer Capacitance | C_{rss} | | | 3.5 | | pF |
| Total Gate Charge | Q_g | $V_{DS}=480V, I_D=5A,$ $V_{GS}=10V$ | | 14.5 | 22 | nC |
| Gate-Source Charge | Q_{gs} | | | 2.8 | | nC |
| Gate-Drain Charge | Q_{gd} | | | 5.5 | | nC |
| Intrinsic gate resistance | R_G | $f = 1 MHz$ open drain | | 2 | | Ω |
| Switching times | | | | | | |
| Turn-on Delay Time | $t_{d(on)}$ | $V_{DD}=480V, I_D=2.5A,$ $R_G=15\Omega, V_{GS}=10V$ | | 7 | | nS |
| Turn-on Rise Time | t_r | | | 5 | | nS |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 70 | 85 | nS |
| Turn-Off Fall Time | t_f | | | 9 | 15 | nS |
| Source- Drain Diode Characteristics | | | | | | |
| Source-drain current(Body Diode) | I_{SD} | $T_C=25^\circ C$ | | | 5 | A |
| Pulsed Source-drain current(Body Diode) | I_{SDM} | | | | 15 | A |
| Forward On Voltage | V_{SD} | $T_J=25^\circ C, I_{SD}=5A, V_{GS}=0V$ | | 0.85 | 1.2 | V |
| Reverse Recovery Time | t_{rr} | $T_J=25^\circ C, I_F=5A, di/dt=100A/\mu s$ | | 240 | | nS |
| Reverse Recovery Charge | Q_{rr} | | | 2.2 | | μC |
| Peak Reverse Recovery Current | I_{rm} | | | 16 | | A |

Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature

2. $T_J=25^\circ C, V_{DD}=50V, V_G=10V, R_G=25\Omega$

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

Figure1. Safe operating area

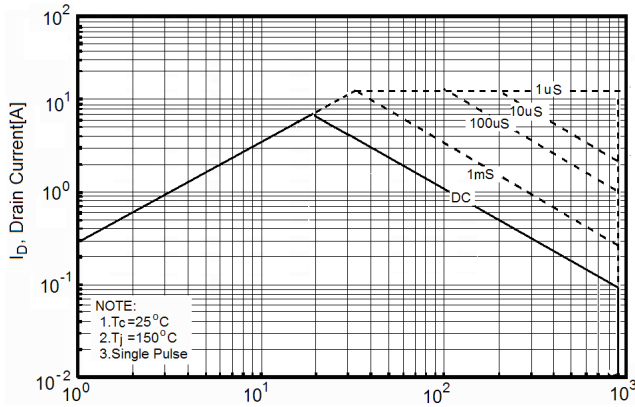


Figure2. Source-Drain Diode Forward Voltage

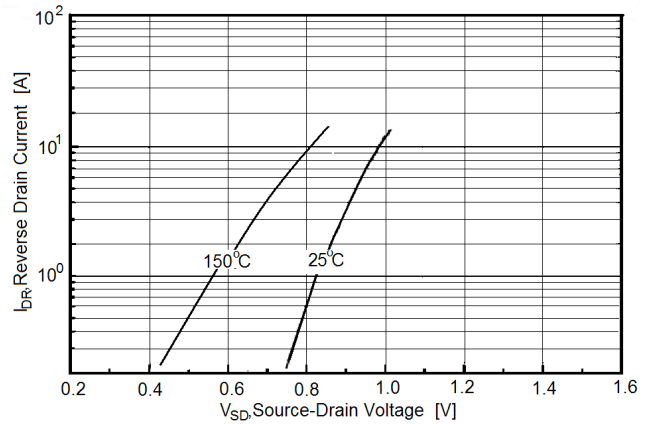


Figure3. Output characteristics

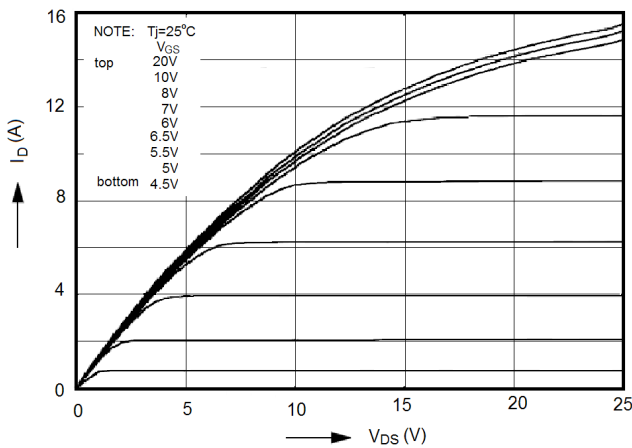


Figure4. Transfer characteristics

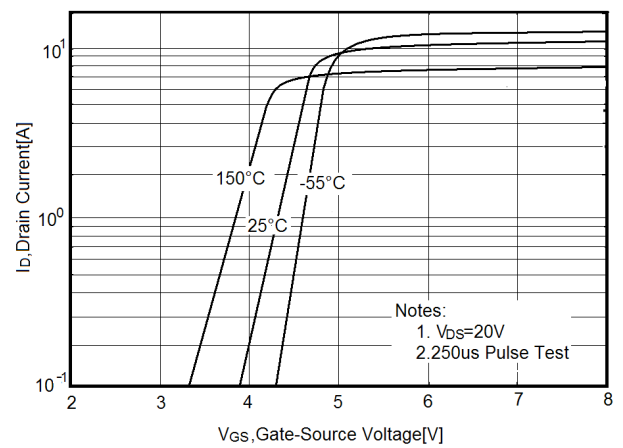


Figure5. Static drain-source on resistance

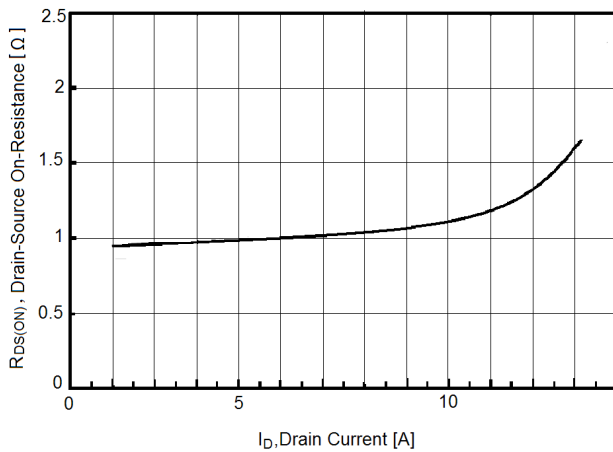


Figure6. RDS(ON) vs Junction Temperature

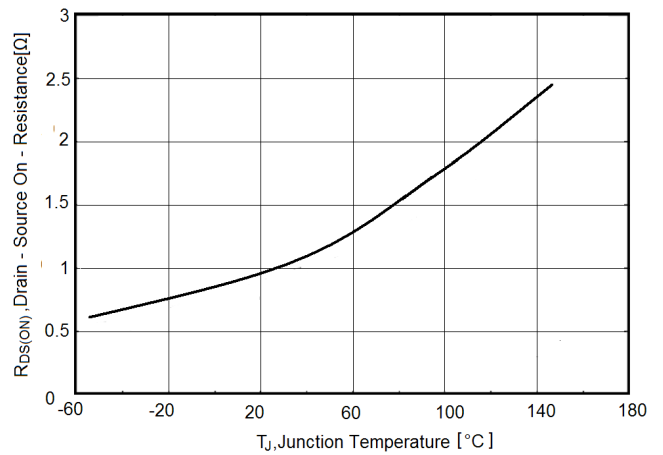


Figure7. BV_{DSS} vs Junction Temperature

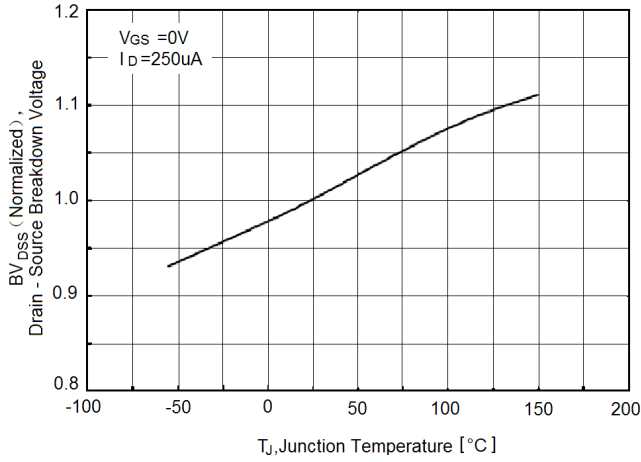


Figure8. Maximum I_D vs Junction Temperature

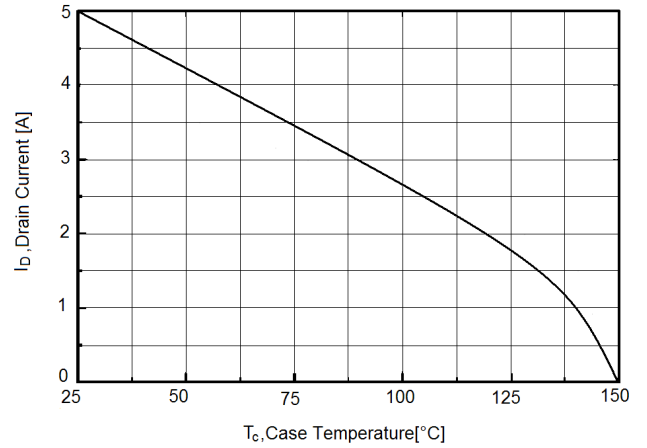


Figure9. Gate charge waveforms

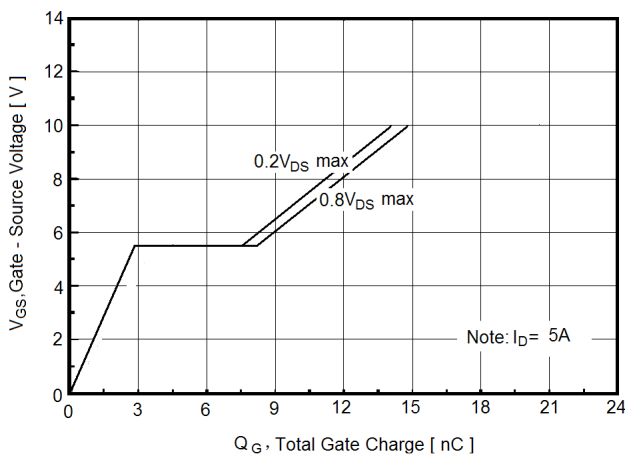


Figure10. Capacitance

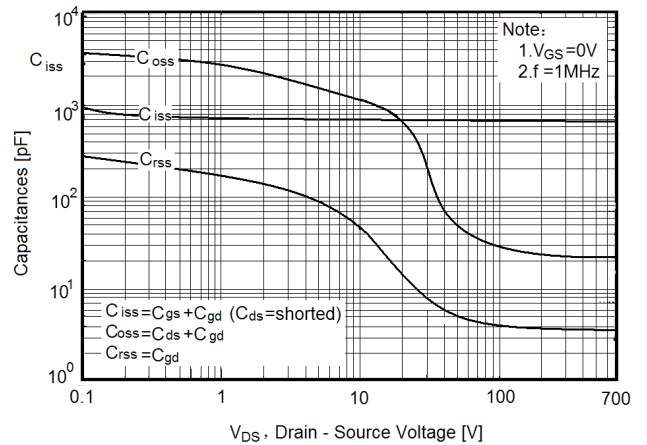
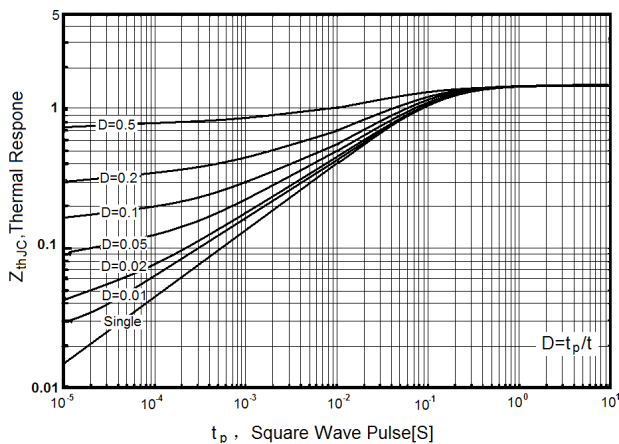
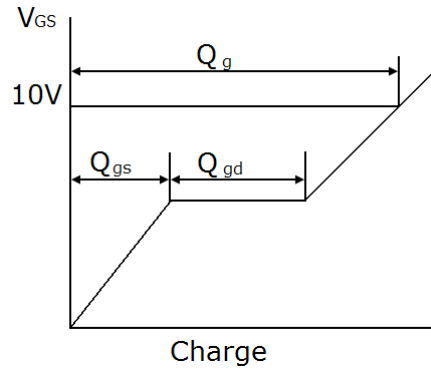
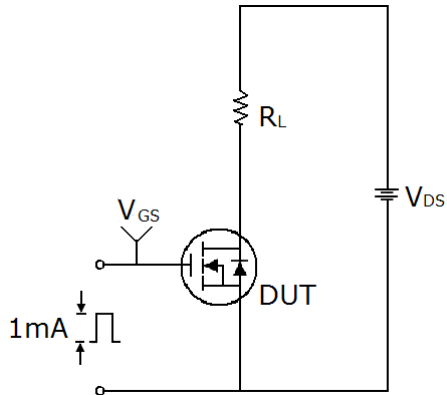


Figure11. Transient Thermal Impedance

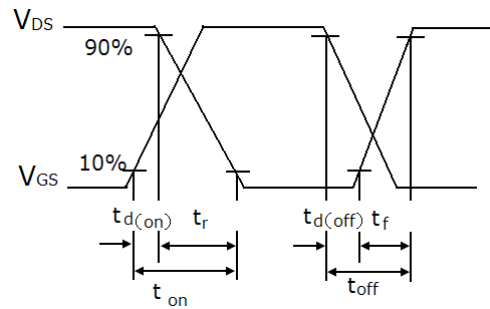
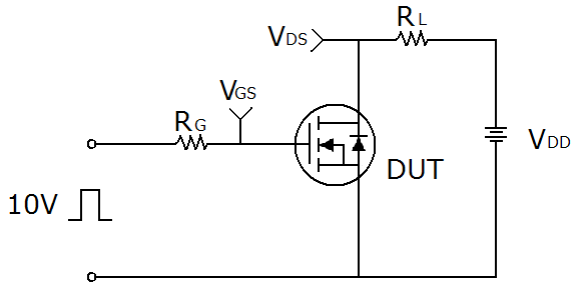


Test circuit

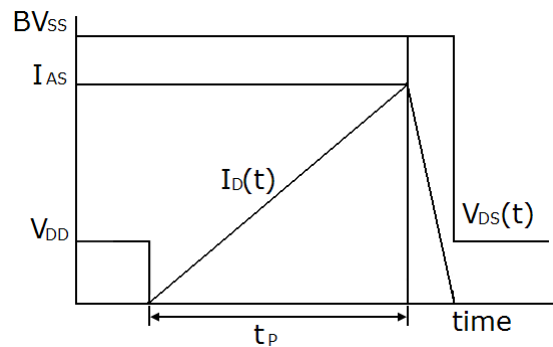
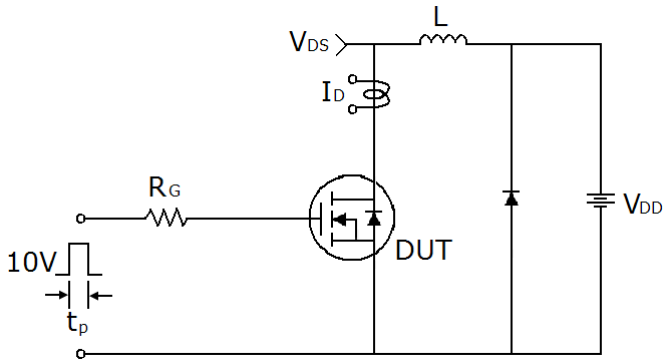
1) Gate charge test circuit & Waveform



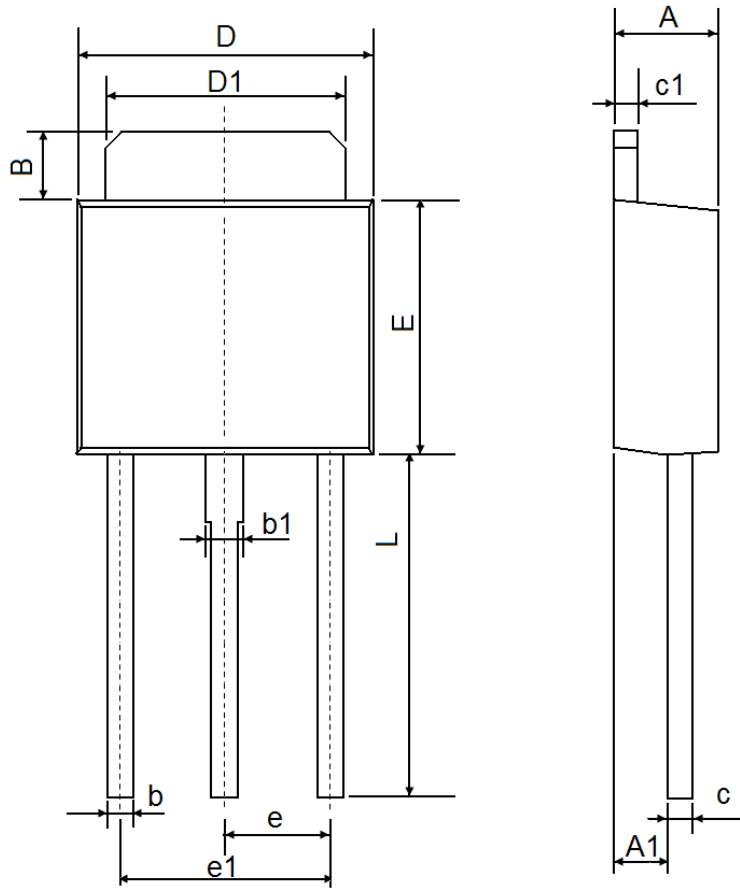
2) Switch Time Test Circuit:



3) Unclamped Inductive Switching Test Circuit & Waveforms

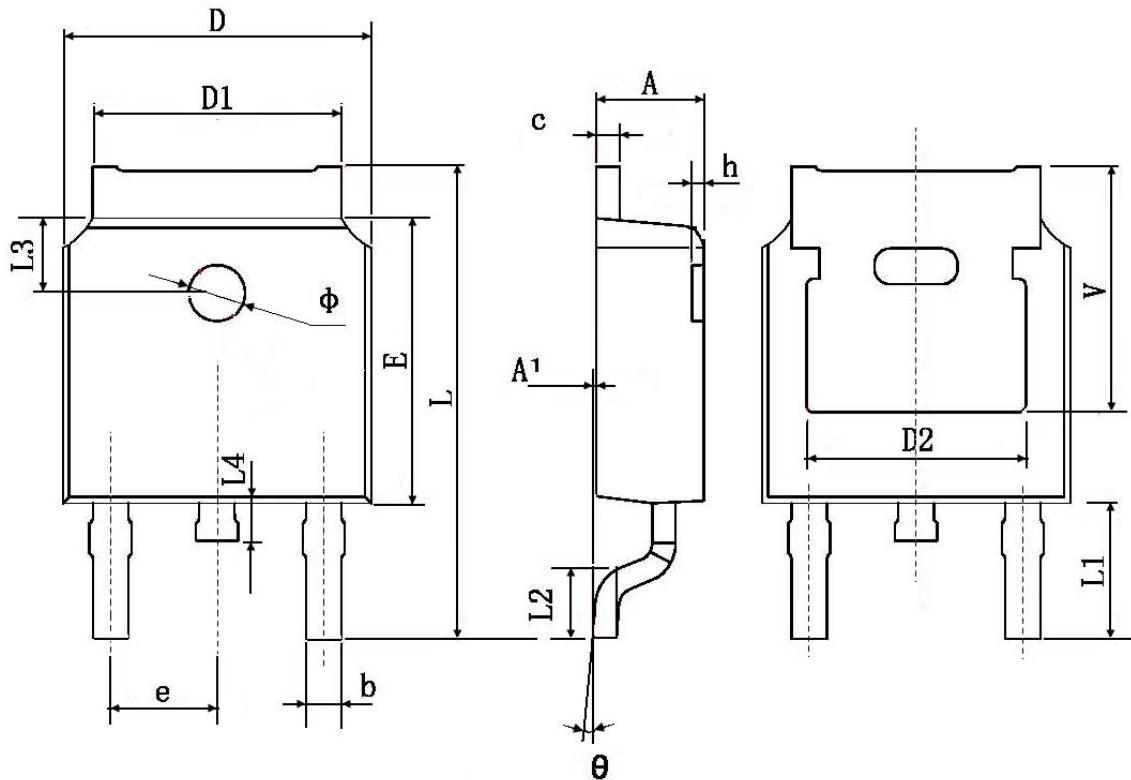


TO-251 Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 2.200 | 2.400 | 0.087 | 0.094 |
| A1 | 1.050 | 1.350 | 0.042 | 0.054 |
| B | 1.350 | 1.650 | 0.053 | 0.065 |
| b | 0.500 | 0.700 | 0.020 | 0.028 |
| b1 | 0.700 | 0.900 | 0.028 | 0.035 |
| c | 0.430 | 0.580 | 0.017 | 0.023 |
| c1 | 0.430 | 0.580 | 0.017 | 0.023 |
| D | 6.350 | 6.650 | 0.250 | 0.262 |
| D1 | 5.200 | 5.400 | 0.205 | 0.213 |
| E | 5.400 | 5.700 | 0.213 | 0.224 |
| e | 2.300 TYP. | | 0.091 TYP. | |
| e1 | 4.500 | 4.700 | 0.177 | 0.185 |
| L | 7.500 | 7.900 | 0.295 | 0.311 |

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| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|--------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 2.200 | 2.400 | 0.087 | 0.094 |
| A1 | 0.000 | 0.127 | 0.000 | 0.005 |
| b | 0.660 | 0.860 | 0.026 | 0.034 |
| c | 0.460 | 0.580 | 0.018 | 0.023 |
| D | 6.500 | 6.700 | 0.256 | 0.264 |
| D1 | 5.100 | 5.460 | 0.201 | 0.215 |
| D2 | 4.830 TYP. | | 0.190 TYP. | |
| E | 6.000 | 6.200 | 0.236 | 0.244 |
| e | 2.186 | 2.386 | 0.086 | 0.094 |
| L | 9.800 | 10.400 | 0.386 | 0.409 |
| L1 | 2.900 TYP. | | 0.114 TYP. | |
| L2 | 1.400 | 1.700 | 0.055 | 0.067 |
| L3 | 1.600 TYP. | | 0.063 TYP. | |
| L4 | 0.600 | 1.000 | 0.024 | 0.039 |
| Φ | 1.100 | 1.300 | 0.043 | 0.051 |
| θ | 0° | 8° | 0° | 8° |
| h | 0.000 | 0.300 | 0.000 | 0.012 |
| V | 5.350 TYP. | | 0.211 TYP. | |

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